

## FEATURES

- 2-Channel Ideal Diode ORing or Load Sharing
- Low Loss Replacement for ORing Diodes
- Low Forward On-Resistance (100mΩ Max at 3.6V)
- Low Reverse Leakage Current (1μA Max)
- Small Regulated Forward Voltage (28mV Typ)
- 2.5V to 5.5V Operating Range
- 2.6A Maximum Forward Current
- Internal Current Limit and Thermal Protection
- Slow Turn-On/Off to Protect Against Inductive Source Impedance-Induced Voltage Spiking
- Ultralow Quiescent Current Consumption, Low Power Alternative to the LTC4413-1
- Status Output to Indicate if Selected Channel is Conducting
- Programmable Channel On/Off
- Low Profile (0.75mm) 10-Lead 3mm × 3mm DFN Package

## APPLICATIONS

- Battery and Wall Adapter Diode ORing in Handheld Products
- Backup Battery Diode ORing
- Power Switching
- USB Peripherals
- Uninterruptable Supplies

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## DESCRIPTION

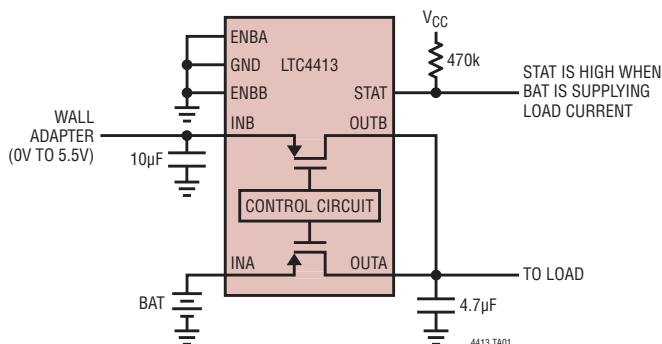
The LTC®4413 contains two monolithic ideal diodes, each capable of supplying up to 2.6A from input voltages between 2.5V and 5.5V. Each ideal diode uses a 100mΩ P-channel MOSFET that independently connects INA to OUTA and INB to OUTB. During normal forward operation the voltage drop across each of these diodes is regulated to as low as 28mV. Quiescent current is less than 40μA for diode currents up to 1A. If either of the output voltages exceeds its respective input voltages, that MOSFET is turned off and less than 1μA of reverse current will flow from OUT to IN. Maximum forward current in each MOSFET is limited to a constant 2.6A and internal thermal limiting circuits protect the part during fault conditions.

Two active-high control pins independently turn off the two ideal diodes contained within the LTC4413, controlling the operation mode as described by Table 1. When the selected channel is reverse biased, or the LTC4413 is put into low power standby, a status signal indicates this condition with a low voltage.

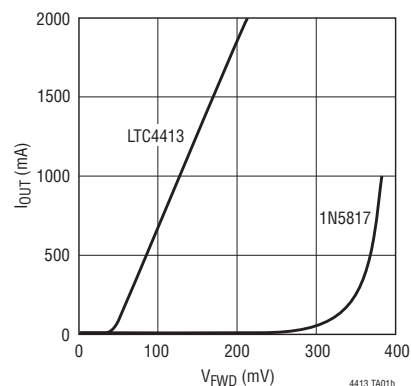
A 9μA open-drain STAT pin is used to indicate conduction status. When terminated to a positive supply through a 470k resistor, the STAT pin can be used to indicate that the selected diode is conducting with a high voltage. This signal can also be used to drive an auxiliary P-channel MOSFET power switch to control a third alternate power source when the LTC4413 is not conducting forward current.

The LTC4413 is housed in a 10-lead DFN package.

## TYPICAL APPLICATION



LTC4413 vs 1N5817 Schottky



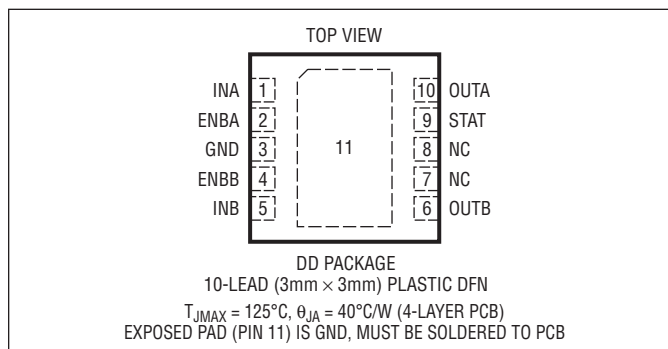
4413fc

## ABSOLUTE MAXIMUM RATINGS

(Note 1)

INA, INB, OUTA, OUTB, STAT,  
 ENBA, ENBB Voltage ..... -0.3V to 6V  
 Operating Temperature Range..... -40°C to 85°C  
 Storage Temperature Range..... -65°C to 125°C  
 Junction Temperature (Note 4) ..... 125°C  
 Continuous Power Dissipation  
 (Derate 25mW/°C Above 70°C)..... 1500mW

## PIN CONFIGURATION



## ORDER INFORMATION

| LEAD FREE FINISH | TAPE AND REEL    | PART MARKING | PACKAGE DESCRIPTION             | TEMPERATURE RANGE |
|------------------|------------------|--------------|---------------------------------|-------------------|
| LTC4413EDD#PBF   | LTC4413EDD#TRPBF | LBGN         | 10-Lead (3mm × 3mm) Plastic DFN | -40°C to 85°C     |

Consult LTC Marketing for parts specified with wider operating temperature ranges.

Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreel/>

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^{\circ}\text{C}$ . (Notes 2, 6)

| SYMBOL            | PARAMETER                                                                                                | CONDITIONS                                                                                             | MIN | TYP | MAX | UNITS         |
|-------------------|----------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------|-----|-----|-----|---------------|
| $V_{IN}, V_{OUT}$ | Operating Supply Range for Channel A or B                                                                | $V_{IN}$ and/or $V_{OUT}$ Must Be in This Range for Proper Operation                                   | ●   | 2.5 | 5.5 | V             |
| UVLO              | UVLO Turn-On Rising Threshold                                                                            | Max ( $V_{INA}, V_{INB}, V_{OUTA}, V_{OUTB}$ )                                                         | ●   |     | 2.4 | V             |
|                   | UVLO Turn-Off Falling Threshold                                                                          | Max ( $V_{INA}, V_{INB}, V_{OUTA}, V_{OUTB}$ )                                                         | ●   | 1.7 |     | V             |
| $I_{QF}$          | Quiescent Current in Forward Regulation (Note 3)                                                         | $V_{INA} = 3.6\text{V}$ , $I_{OUTA} = -100\text{mA}$ , $V_{INB} = 0\text{V}$ , $I_{OUTB} = 0\text{mA}$ | ●   | 25  | 40  | $\mu\text{A}$ |
| $I_{QRIN}$        | Quiescent Current While in Reverse Turn-Off, Current Drawn from $V_{IN}$                                 | $V_{IN} = 3.6\text{V}$ , $V_{OUT} = 5.5\text{V}$ (Note 6)                                              | ●   | -1  | 0.5 | $\mu\text{A}$ |
| $I_{QRGND}$       | Quiescent Current While in Reverse Turn-Off, Measured Via GND                                            | $V_{INA} = V_{INB} = V_{OUTB} = 0\text{V}$ , $V_{OUTA} = 5.5\text{V}$ , $V_{STAT} = 0\text{V}$         |     | 22  | 30  | $\mu\text{A}$ |
| $I_{QROUTA}$      | Quiescent Current While in Reverse Turn-Off, Current Drawn from $V_{OUTA}$ When OUTA Supplies Chip Power | $V_{INA} = V_{INB} = V_{OUTB} = 0\text{V}$ , $V_{OUTA} = 5.5\text{V}$                                  | ●   | 17  | 31  | $\mu\text{A}$ |
| $I_{QROUTB}$      | Quiescent Current While in Reverse Turn-Off, Current Drawn from $V_{OUTA}$ When OUTB Supplies Chip Power | $V_{INA} = V_{INB} = 0\text{V}$ , $V_{OUTA} < V_{OUTB} = 5.5\text{V}$                                  | ●   | 2   | 3   | $\mu\text{A}$ |
| $I_{QOFF}$        | Quiescent Current with Both ENBA and ENBB High                                                           | $V_{INA} = V_{INB} = 3.6\text{V}$ , $V_{ENBA}$ and $V_{ENBB}$ High, $V_{STAT} = 0\text{V}$             | ●   | 20  | 31  | $\mu\text{A}$ |

# ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ . (Notes 2, 6)

| SYMBOL            | PARAMETER                                                                                               | CONDITIONS                                                                                   | MIN | TYP | MAX | UNITS            |
|-------------------|---------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|-----|-----|-----|------------------|
| $I_{\text{LEAK}}$ | $V_{\text{INA}}$ or $V_{\text{INB}}$ Current When $V_{\text{OUTA}}$ or $V_{\text{OUTB}}$ Supplies Power | $V_{\text{IN}} = 0\text{V}$ , $V_{\text{OUT}} = 5.5\text{V}$                                 | -1  |     | 1   | $\mu\text{A}$    |
| $V_{\text{RTO}}$  | Reverse Turn-Off Voltage ( $V_{\text{OUT}} - V_{\text{IN}}$ )                                           | $V_{\text{IN}} = 3.6\text{V}$                                                                | -5  |     | 10  | mV               |
| $V_{\text{FWD}}$  | Forward Voltage Drop ( $V_{\text{IN}} - V_{\text{OUT}}$ ) at $I_{\text{OUT}} = -1\text{mA}$             | $V_{\text{IN}} = 3.6\text{V}$                                                                | ●   | 28  | 38  | mV               |
| $R_{\text{FWD}}$  | On-Resistance, $R_{\text{FWD}}$ Regulation (Measured as $\Delta V/\Delta I$ )                           | $V_{\text{IN}} = 3.6\text{V}$ , $I_{\text{OUT}} = -100\text{mA}$ to $-500\text{mA}$ (Note 5) |     | 100 | 140 | $\text{m}\Omega$ |
| $R_{\text{ON}}$   | On-Resistance, $R_{\text{ON}}$ Regulation (Measured as $V/I$ at $I_{\text{IN}} = 1\text{A}$ )           | $V_{\text{IN}} = 3.6\text{V}$ , $I_{\text{OUT}} = -1.0\text{A}$ (Note 5)                     |     | 140 | 200 | $\text{m}\Omega$ |
| $t_{\text{ON}}$   | PowerPath™ Turn-On Time                                                                                 | $V_{\text{IN}} = 3.6\text{V}$ , from ENB Falling to $I_{\text{IN}}$ Ramp Starting (Note 7)   |     | 50  |     | $\mu\text{s}$    |
| $t_{\text{OFF}}$  | PowerPath Turn-Off Time                                                                                 | $V_{\text{IN}} = 3.6\text{V}$ , $I_{\text{OUT}} = -100\text{mA}$ (Note 7)                    |     | 4   |     | $\mu\text{s}$    |

## Short-Circuit Response

|                  |                                                  |                                                                              |     |     |     |               |
|------------------|--------------------------------------------------|------------------------------------------------------------------------------|-----|-----|-----|---------------|
| $I_{\text{OC}}$  | Current Limit                                    | $V_{\text{INX}} = 3.6\text{V}$ (Notes 4, 5)                                  | 1.8 |     |     | A             |
| $I_{\text{QOC}}$ | Quiescent Current While in Overcurrent Operation | $V_{\text{INX}} = 3.6\text{V}$ , $I_{\text{OUT}} = 1.9\text{A}$ (Notes 4, 5) |     | 150 | 300 | $\mu\text{A}$ |

## STAT Output

|                     |                        |                                                                                                            |   |    |   |    |               |
|---------------------|------------------------|------------------------------------------------------------------------------------------------------------|---|----|---|----|---------------|
| $I_{\text{SOFF}}$   | STAT Off Current       | Shutdown                                                                                                   | ● | -1 | 0 | 1  | $\mu\text{A}$ |
| $I_{\text{SON}}$    | STAT Sink Current      | $V_{\text{IN}} > V_{\text{OUT}}$ , $V_{\text{ENB}} < V_{\text{ENBIL}}$ , $I_{\text{OUT}} < I_{\text{MAX}}$ |   | 7  | 9 | 17 | $\mu\text{A}$ |
| $t_{\text{S(ON)}}$  | STAT Pin Turn-On Time  |                                                                                                            |   |    | 1 |    | $\mu\text{s}$ |
| $t_{\text{S(OFF)}}$ | STAT Pin Turn-Off Time |                                                                                                            |   |    | 1 |    | $\mu\text{s}$ |

## ENB Inputs

|                     |                                      |                                                                                      |   |     |     |     |               |
|---------------------|--------------------------------------|--------------------------------------------------------------------------------------|---|-----|-----|-----|---------------|
| $V_{\text{ENBIH}}$  | ENB Inputs Rising Threshold Voltage  | $V_{\text{ENB}}$ Rising                                                              | ● |     | 540 | 600 | mV            |
| $V_{\text{ENBIL}}$  | ENB Inputs Falling Threshold Voltage | $V_{\text{ENB}}$ Falling                                                             | ● | 400 | 460 |     | mV            |
| $V_{\text{ENBHYS}}$ | ENB Inputs Hysteresis                | $V_{\text{ENBHYS}} = (V_{\text{ENBIH}} - V_{\text{ENBIL}})$                          |   |     | 90  |     | mV            |
| $I_{\text{ENB}}$    | ENB Inputs Pull-Down Current         | $V_{\text{OUT}} < V_{\text{IN}} = 3.6\text{V}$ , $V_{\text{ENB}} > V_{\text{ENBIL}}$ | ● | 1.5 | 3   | 4.5 | $\mu\text{A}$ |

PowerPath is a trademark of Linear Technology Corporation.

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** The LTC4413 is guaranteed to meet performance specifications from  $0^\circ\text{C}$  to  $85^\circ\text{C}$ . Specifications over the  $-40^\circ\text{C}$  to  $85^\circ\text{C}$  operating temperature range are assured by design, characterization and correlation with statistical process controls.

**Note 3:** Quiescent current increases with diode current, refer to plot of  $I_{\text{QF}}$  vs  $I_{\text{OUT}}$ .

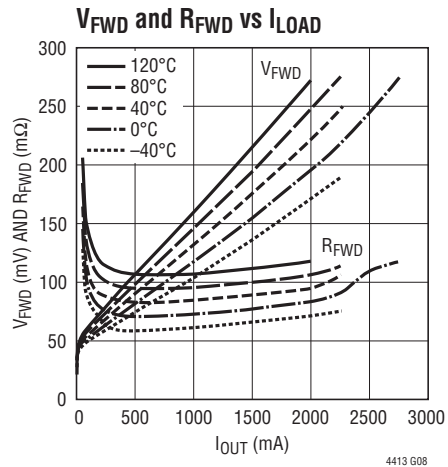
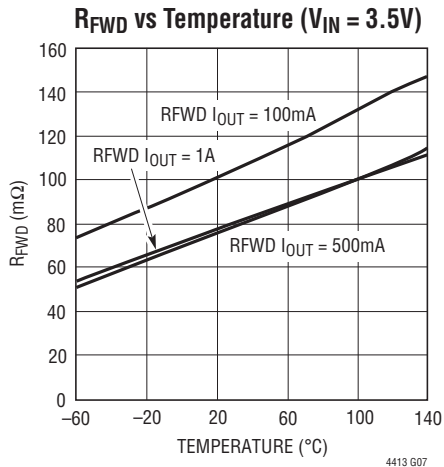
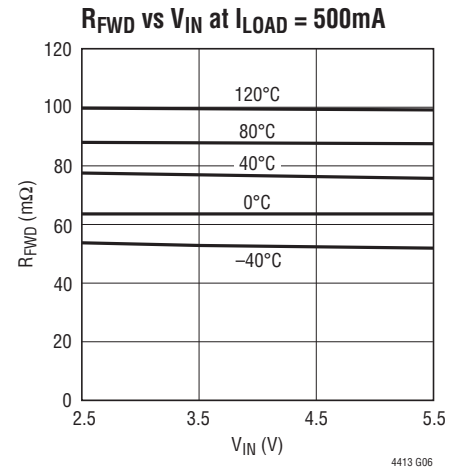
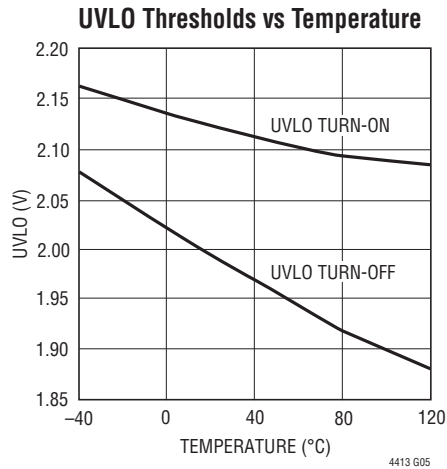
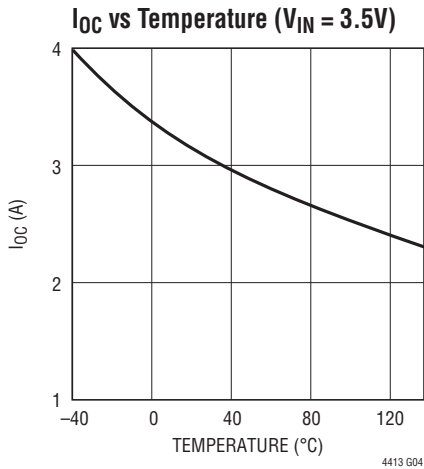
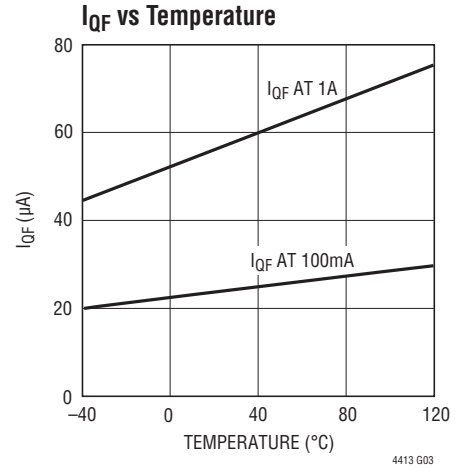
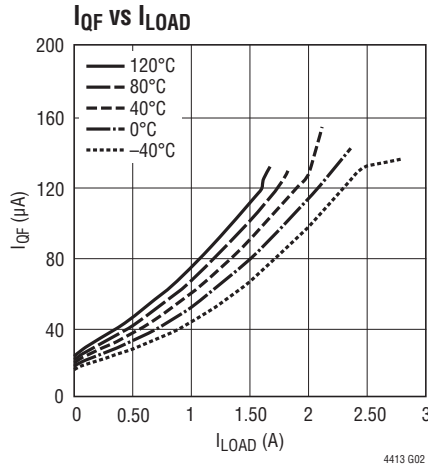
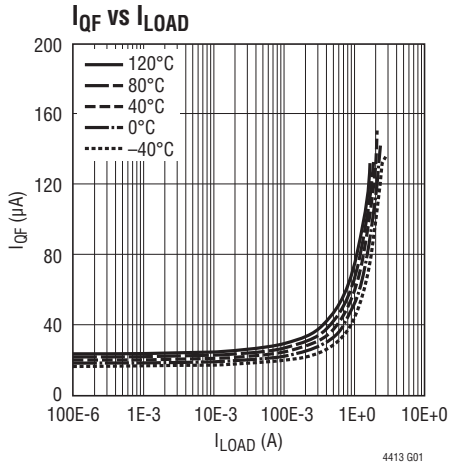
**Note 4:** This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Overtemperature protection will become active at a junction temperature greater than the maximum operating temperature. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

**Note 5:** This specification is guaranteed by correlation to wafer-level measurements.

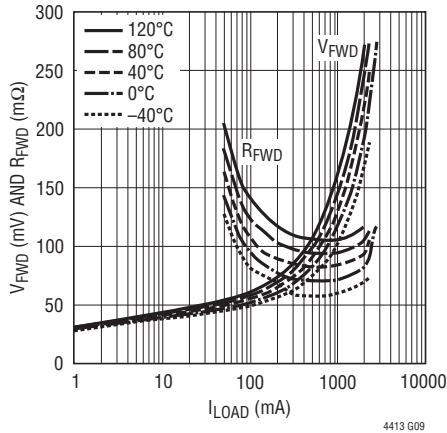
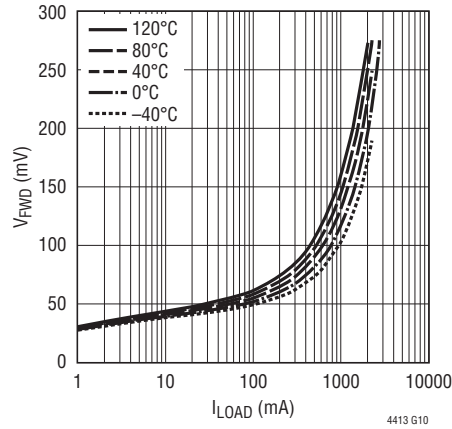
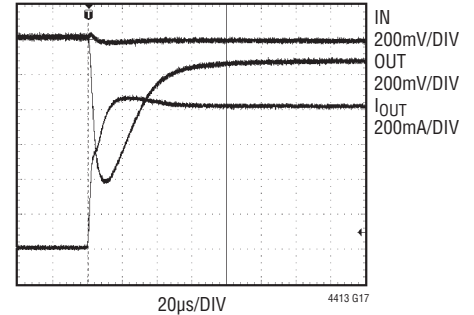
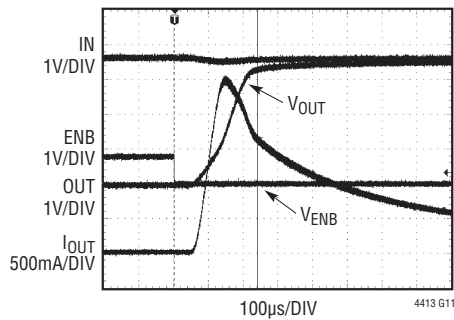
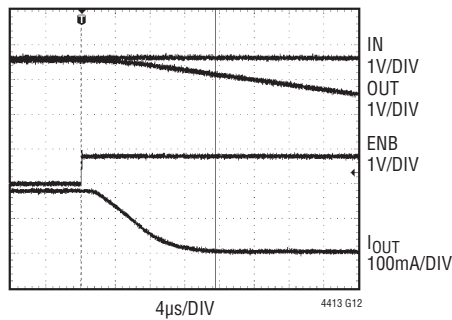
**Note 6:** Unless otherwise specified, current into a pin is positive and current out of a pin is negative. All voltages referenced to GND.

**Note 7:** Guaranteed by design.

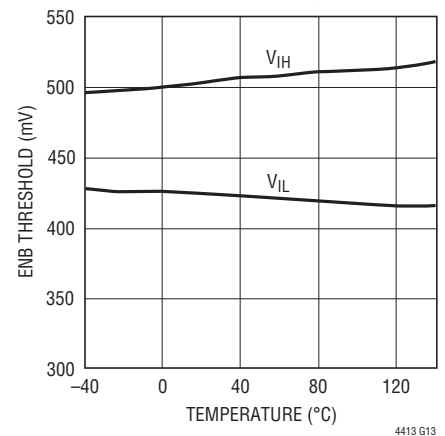
## TYPICAL PERFORMANCE CHARACTERISTICS



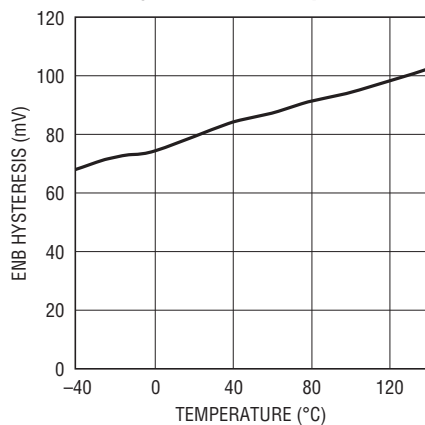
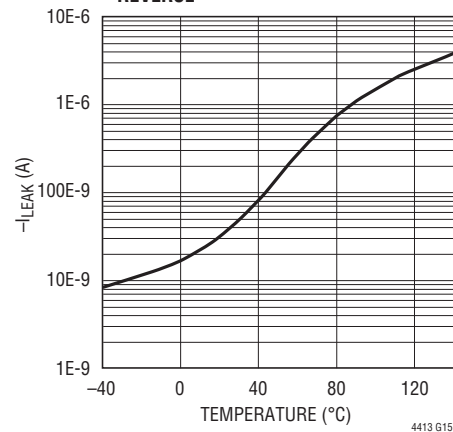
## TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{FWD}$  and  $R_{FWD}$  vs  $I_{LOAD}$  $V_{FWD}$  vs  $I_{LOAD}$  ( $V_{IN} = 3.5V$ )Response to 800mA Load Step in 80 $\mu$ sENB Turn-On, 240 $\mu$ s to Recover with 180mA LoadENB Turn-Off, 16 $\mu$ s to Disconnect IN from 180mA Load

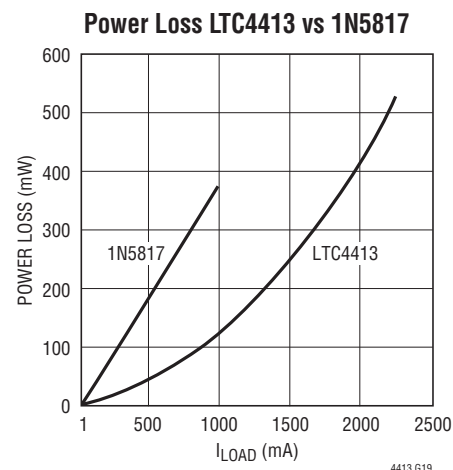
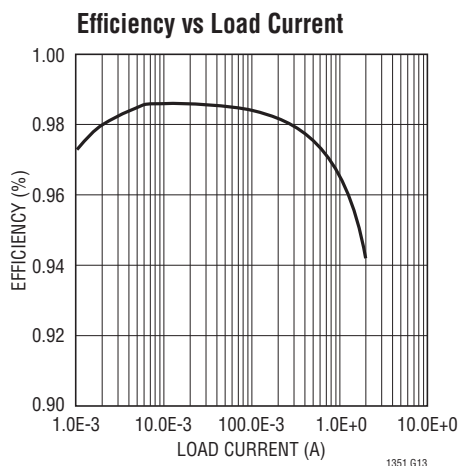
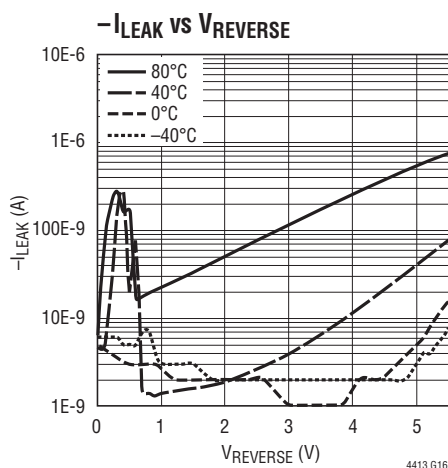
ENB Threshold vs Temperature



ENB Hysteresis vs Temperature

 $-I_{LEAK}$  vs Temperature at  $V_{REVERSE} = 5.5V$ 

## TYPICAL PERFORMANCE CHARACTERISTICS



## PIN FUNCTIONS

**INA (Pin 1):** Primary Ideal Diode Anode and Positive Power Supply. Bypass INA with a ceramic capacitor of at least 1 $\mu$ F. 1 $\Omega$  snub resistors in series with a capacitor and higher valued capacitances are recommended when large inductances are in series with this input. Limit slew rate on this pin to less than 0.5V/ $\mu$ s. This pin can be grounded when not used.

**ENBA (Pin 2):** Enable Low for Diode A. Weak (3 $\mu$ A) pull-down. Pull this pin high to shut down this power path. Tie to GND to enable. Refer to Table 1 for mode control functionality. This pin can be left floating, weak pull-down internal to the LTC4413.

**GND (Pins 3, 11):** Power and Signal Ground for the IC. The exposed pad of the package, Pin 11, must be soldered to PCB ground to provide both electrical contact to ground and good thermal contact to the PCB.

**ENBB (Pin 4):** Enable Low for Diode B. Weak (3 $\mu$ A) pull-down. Pull this pin high to shut down this power path. Tie to GND to enable. Refer to Table 1 for mode control functionality. This pin can be left floating, weak pull-down internal to the LTC4413.

**INB (Pin 5):** Secondary Ideal Diode Anode and Positive Power Supply. Bypass INB with a ceramic capacitor of at least 1 $\mu$ F. 1 $\Omega$  snub resistors in series with a capacitor and

higher valued capacitances are recommended when large inductances are in series with this input. Limit slew rate on this pin to less than 0.5V/ $\mu$ s. This pin can be grounded when not used.

**OUTB (Pin 6):** Secondary Ideal Diode Cathode and Output. Bypass OUTB with a high (1m $\Omega$  min) ESR ceramic capacitor of at least 4.7 $\mu$ F. Limit slew rate on this pin to less than 0.5V/ $\mu$ s. This pin must be left floating when not in use.

**NC (Pin 7):** No Internal Connection.

**NC (Pin 8):** No Internal Connection.

**STAT (Pin 9):** Status Condition Indicator. Weak (9 $\mu$ A) pull-down current output. When terminated, STAT = high indicates diode conducting.

The function of the STAT pin depends on the mode that has been selected. Table 2 describes the STAT pin output current as a function of the mode selected as well as the conduction state of the two diodes. This pin can also be left floating or grounded.

**OUTA (Pin 10):** Primary Ideal Diode Cathode and Output. Bypass OUTA with a high (1m $\Omega$  min) ESR ceramic capacitor of at least 4.7 $\mu$ F. Limit slew rate on this pin to less than 0.5V/ $\mu$ s. This pin must be left floating when not in use.





## OPERATION

The LTC4413 is described with the aid of the Block Diagram (Figure 1). Operation begins when the power source at  $V_{INA}$  or  $V_{INB}$  rises above the undervoltage lockout (UVLO) voltage of 2.4V and either of the ENBA or ENBB control pins is low. If only the voltage at the  $V_{INA}$  pin is present, the power source to the LTC4413 ( $V_{DD}$ ) will be supplied from the  $V_{INA}$  pin. The amplifier (A) pulls a current proportional to the difference between  $V_{INA}$  and  $V_{OUTA}$  from the gate ( $V_{GATEA}$ ) of the internal PFET (PA), driving this gate voltage below  $V_{INA}$ . This turns on PA. As  $V_{OUTA}$  is pulled up to a forward voltage drop ( $V_{FWD}$ ) of 20mV below  $V_{INA}$ , the LTC4413 regulates  $V_{GATEA}$  to maintain the small forward voltage drop. The system is now in forward regulation and the load at  $V_{OUTA}$  is powered from the supply at  $V_{INA}$ . As the load current varies,  $V_{GATEA}$  is controlled to maintain  $V_{FWD}$  until the load current exceeds the transistor's (PA) ability to deliver the current as  $V_{GATEA}$  approaches GND. At this point the PFET behaves as a fixed resistor with resistance  $R_{ON}$ , whereby the forward voltage increases slightly with increased load current. As the magnitude of  $I_{OUT}$  increases further (such that  $I_{LOAD} > I_{OC}$ ), the LTC4413 fixes the load current to the constant value  $I_{OC}$  to protect the device. The characteristics for parameters  $R_{FWD}$ ,  $R_{ON}$ ,  $V_{FWD}$  and  $I_{OC}$  are specified with the aid of Figure 2, illustrating the LTC4413 forward voltage drop versus that of a Schottky diode.

If another supply is provided at  $V_{INB}$ , the LTC4413 likewise regulates the gate voltage on PB to maintain the output voltage  $V_{OUTB}$  just below the input voltage  $V_{INB}$ . If this

alternate supply,  $V_{INB}$ , exceeds the voltage at  $V_{INA}$ , the LTC4413 selects this input voltage as the internal supply ( $V_{DD}$ ). This second ideal diode operates independently of the first ideal diode function.

When an alternate power source is connected to the load at  $V_{OUTA}$  (or  $V_{OUTB}$ ), the LTC4413 senses the increased voltage at  $V_{OUTA}$  and amplifier A increases the voltage  $V_{GATEA}$ , reducing the current through PA. When  $V_{OUTA}$  is higher than  $V_{INA} + V_{RTO}$ ,  $V_{GATEA}$  is pulled up to  $V_{DD}$ , which turns off PA. The internal power source for the LTC4413 ( $V_{DD}$ ) is then diverted to source current from the  $V_{OUTA}$  pin, only if  $V_{OUTA}$  is larger than  $V_{INB}$  (or  $V_{OUTB}$ ). The system is now in the reverse turn-off mode. Power to the load is being delivered from an alternate supply and only a small current is drawn from  $V_{INA}$  to sense the potential at  $V_{INA}$ .

When the selected channel of the LTC4413 is in reverse turn-off mode or both channels are disabled, the STAT pin sinks 9 $\mu$ A of current ( $I_{SON}$ ) if connected.

Channel selection is accomplished using the two ENB pins, ENBA and ENBB. When the ENBA input is asserted (high), PA's gate voltage is pulled to  $V_{DD}$  at a controlled rate, limiting the turn-off time to avoid voltage spiking at the input when being driven by an inductive source impedance. A 3 $\mu$ A pull-down current on the ENB pins ensures a low level at these inputs if left floating.

### Slow Response Time

The LTC4413-1 (or LTC4413-2) is recommended for applications with demanding load step or fast slew rate requirements. The LTC4413-1 and LTC4413-2 provide better load regulation in these environments at the expense of higher quiescent current. The LTC4413 is optimized for lower power consumption and should not be used in high slew rate environments or when large and fast load transients are anticipated.

### Overcurrent and Short-Circuit Protection

During an overcurrent condition, the output voltage droops as the load current exceeds the amount of current that the LTC4413 can supply. At the time when an overcurrent condition is first detected, the LTC4413 takes some time to detect this condition before reducing the current to  $I_{MAX}$ .

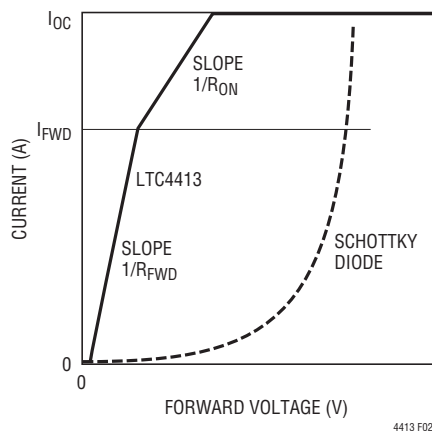


Figure 2

4413 F02



## OPERATION

For short durations after the output is shorted, the current may exceed  $I_{MAX}$ . The magnitude of this peak short-circuit current can be large, depending on the load current immediately before the short circuit occurs. During overcurrent operation, the power consumption of the LTC4413 is large, and is likely to cause an overtemperature condition as the internal die temperature exceeds the thermal shutdown temperature.

### Overtemperature Protection

The overtemperature condition is detected when the internal die temperature increases beyond 150°C. An overtemperature condition causes the gate amplifiers (A and B) as well as the two P-channel MOSFETs (PA and PB) to be shut off. When the internal die temperature cools to below 140°C, the amplifiers turn on and revert to normal operation. Note that prolonged operation under overtemperature conditions degrades reliability.

### Channel Selection and Status Output

Two active-high control pins independently turn off the two ideal diodes contained within the LTC4413, controlling the operation mode as described by Table 1. When the selected channel is reverse biased, or the LTC4413 is put into low power standby, the status signal indicates this condition with a low voltage.

**Table 1. Mode Control**

| ENB1 | ENB2 | STATE                                                                   |
|------|------|-------------------------------------------------------------------------|
| Low  | Low  | Diode OR (NB: The Two Outputs Are Not Connected Internal to the Device) |
| Low  | High | Diode A = Enabled, Diode B = Disabled                                   |
| High | Low  | Diode A = Disabled, Diode B = Enabled                                   |
| High | High | All Off (Low Power Standby)                                             |

The function of the STAT pin depends on the mode that has been selected. The following table describes the STAT pin output current as a function of the mode selected, as well as the conduction state of the two diodes.

**Table 2. STAT Output Pin Function**

| ENB1 | ENB2 | CONDITIONS                                 | STAT               |
|------|------|--------------------------------------------|--------------------|
| Low  | Low  | Diode A Forward Bias, Diode B Forward Bias | $I_{SNK} = 0\mu A$ |
|      |      | Diode A Forward Bias, Diode B Reverse Bias | $I_{SNK} = 0\mu A$ |
|      |      | Diode A Reverse Bias, Diode B Forward Bias | $I_{SNK} = 9\mu A$ |
|      |      | Diode A Reverse Bias, Diode B Reverse Bias | $I_{SNK} = 9\mu A$ |
| Low  | High | Diode A Forward Bias, Diode B Disabled     | $I_{SNK} = 0\mu A$ |
|      |      | Diode A Reverse Bias, Diode B Disabled     | $I_{SNK} = 9\mu A$ |
| High | Low  | Diode A Disabled, Diode B Forward Bias     | $I_{SNK} = 0\mu A$ |
|      |      | Diode A Disabled, Diode B Reverse Bias     | $I_{SNK} = 9\mu A$ |
| High | High | Diode A Disabled, Diode B Disabled         | $I_{SNK} = 9\mu A$ |

## APPLICATIONS INFORMATION

### Introduction

The LTC4413 is intended for power control applications that include low loss diode ORing, fully automatic switchover from a primary to an auxiliary source of power, microcontroller controlled switchover from a primary to an auxiliary source of power, load sharing between two or more batteries, charging of multiple batteries from a single charger and high side power switching. The LTC4413 is optimized for low quiescent power consumption at the expense of transient response. For more demanding slew

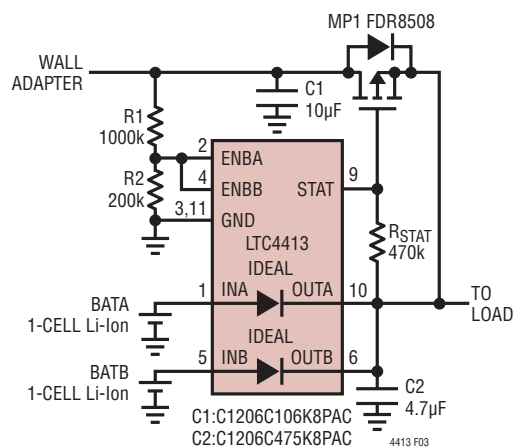
rate or load transient applications, the pin compatible LTC4413-1 is recommended.

### Dual Battery Load Sharing with Automatic Switchover to a Wall Adapter

An application circuit for dual battery load sharing with automatic switchover of load from batteries to a wall adapter is shown in Figure 3. When the wall adapter is not present, whichever battery that has the higher voltage provides the load current until it has discharged to the voltage of the other battery. The load is then shared between the two

4413fc

## APPLICATIONS INFORMATION

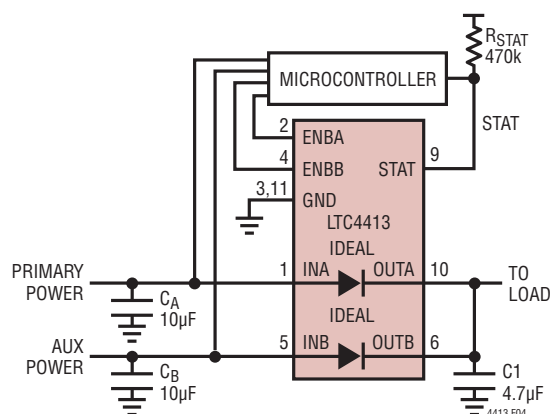


### Figure 3

batteries according to the capacity of each battery. The higher capacity battery provides proportionally higher current to the load. When a wall adapter input is applied, the voltage divider formed by R1 and R2 disables the LTC4413, causing the STAT pin voltage to fall, turning on MP1. At this point the load is powered by the wall adapter and both batteries may be removed without interrupting the load voltage. When the wall adapter is removed, the output voltage droops until the voltage divider turns on the LTC4413, at which point the batteries revert to providing load power. The status signal can also be used to provide information as to whether the wall adapter (or BATB) is supplying the load current.

## Automatic PowerPath Control

Figure 4 illustrates an application circuit for microcontroller monitoring and control of two power sources. The

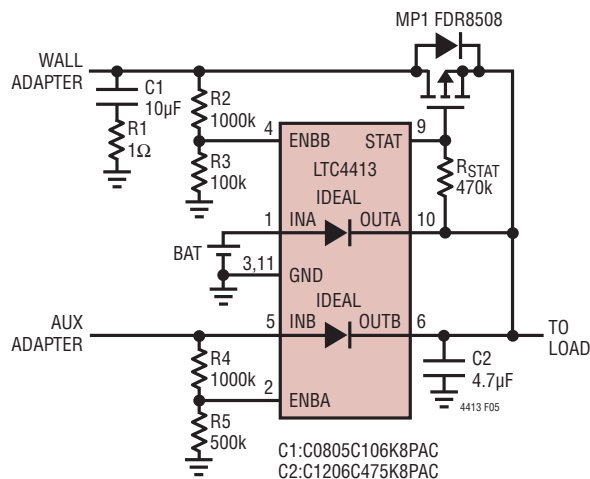


### Figure 4

microcontroller's analog inputs (perhaps with the aid of a resistor voltage divider) monitors each supply input and the LTC4413 status, and then commands the LTC4413 through the two ENBA/ENBB control inputs.

## Automatic Switchover from a Battery to an Auxiliary Supply or a Wall Adapter

Figure 5 illustrates an application for implementing the function of automatic switchover from a battery to either an auxiliary supply or to a wall adapter using the LTC4413. The LTC4413 automatically senses the presence of a wall adapter as the ENBB pin voltage is pulled higher than its rising turn-off threshold of 550mV through resistive divider (R2 and R3). This disables the AUX input from powering the load. If the AUX is not present when a wall adapter is attached (i.e., the BAT is supplying load current), as the wall adapter voltage rises, the body diode in MP1 forward biases, pulling the output voltage above the BAT voltage. The LTC4413 senses a reverse voltage of as little as 10mV and turns off the ideal diode between INA and OUTA. This causes the STAT voltage to fall, turning on MP1. The load then draws current from the wall adapter, and the battery is disconnected from the load. If the AUX is not present when the wall adapter is removed, the load voltage droops until the BAT voltage exceeds the load voltage. The LTC4413 senses that the BAT voltage is greater, causing the STAT voltage to rise, disabling MP1; the BAT then provides power to the load.

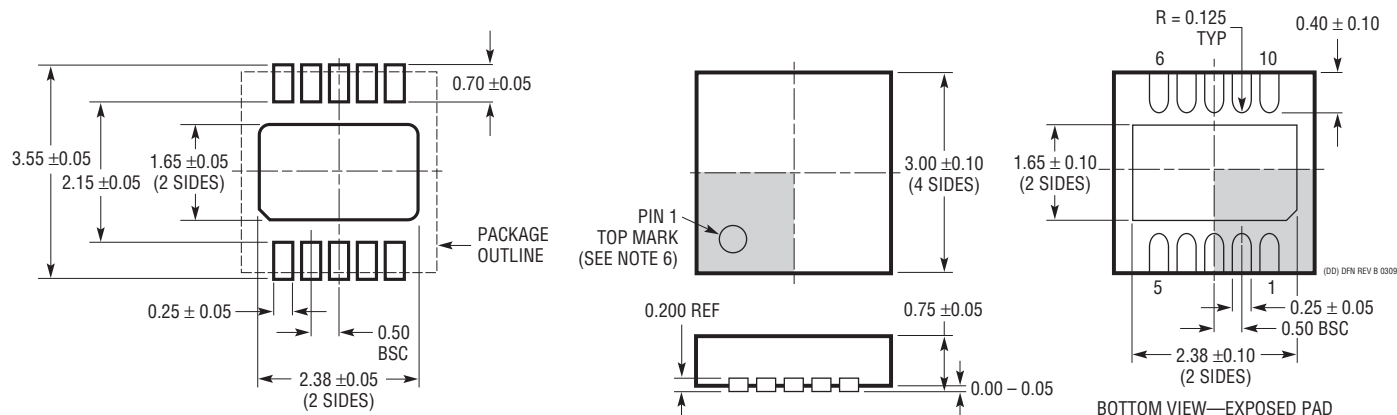


### Figure 5



## PACKAGE DESCRIPTION

**DD Package**  
**10-Lead Plastic DFN (3mm × 3mm)**  
 (Reference LTC DWG # 05-08-1699 Rev B)



### RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS

#### NOTE:

1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE MO-229 VARIATION OF (WEED-2).  
CHECK THE LTC WEBSITE DATA SHEET FOR CURRENT STATUS OF VARIATION ASSIGNMENT
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

## RELATED PARTS

| PART NUMBER         | DESCRIPTION                                                                       | COMMENTS                                                                                                                                                         |
|---------------------|-----------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| LTC1558/LTC1559     | Backup Battery Controller with Programmable Output                                | Adjustable Backup Voltage from 1.2V NiCd Button Cell, Includes Boost Converter                                                                                   |
| LTC1998             | 2.5μA, 1% Accurate Programmable Battery Detector                                  | Adjustable Trip Voltage/Hysteresis, ThinSOT™                                                                                                                     |
| LTC4054             | 800mA Standalone Linear Li-Ion Battery Charger with Thermal Regulation in ThinSOT | No External MOSFET, Sense Resistor or Blocking Diode Required, Charge Current Monitor for Gas Gauging, C/10 Charge Termination                                   |
| LTC4055             | USB Power Controller and Li-Ion Charger                                           | Automatic Switchover, Charges 1-Cell Li-Ion Batteries                                                                                                            |
| LTC4085             | USB Power Manager with Ideal Diode Controller and Li-Ion Charger                  | Charges Single Cell Li-Ion Batteries Directly from a USB Port, Thermal Regulation, 200mΩ Ideal Diode with <50mΩ Option, 4mm × 3mm 14-Lead DFN Package            |
| LTC4350             | Hot Swappable Load Share Controller                                               | Allows N + 1 Redundant Supply, Equally Loads Multiple Power Supplies Connected in Parallel                                                                       |
| LTC4351             | MOSFET Diode-OR Controller                                                        | 1.2V to 18V Input, Internal Boost Regulator for Driving N-Channel MOSFET                                                                                         |
| LTC4411             | 2.6A Low Loss Ideal Diode in ThinSOT Load Sharing                                 | No External MOSFET, Automatic Switching Between DC Sources, Simplified                                                                                           |
| LTC4412/LTC4412HV   | PowerPath Controllers in ThinSOT                                                  | More Efficient than Diode ORing, Automatic Switching Between DC Sources, Simplified Load Sharing, 3V ≤ V <sub>IN</sub> ≤ 28V (3V ≤ V <sub>IN</sub> ≤ 36V for HV) |
| LTC4413-1/LTC4413-2 | Dual 2.6A, 2.5V to 5.5V Fast Ideal Diodes in 3mm × 3mm DFN                        | Fast Pin Compatible Replacement for the LTC4413 (LTC4413-2 with Overvoltage Protection)                                                                          |

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